

# **Study of the evolution of the energy performance of photovoltaic systems under different aging conditions**

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## **I. Diversity of photovoltaic (PV) systems**

## **II. Degradation of PV modules and approach**

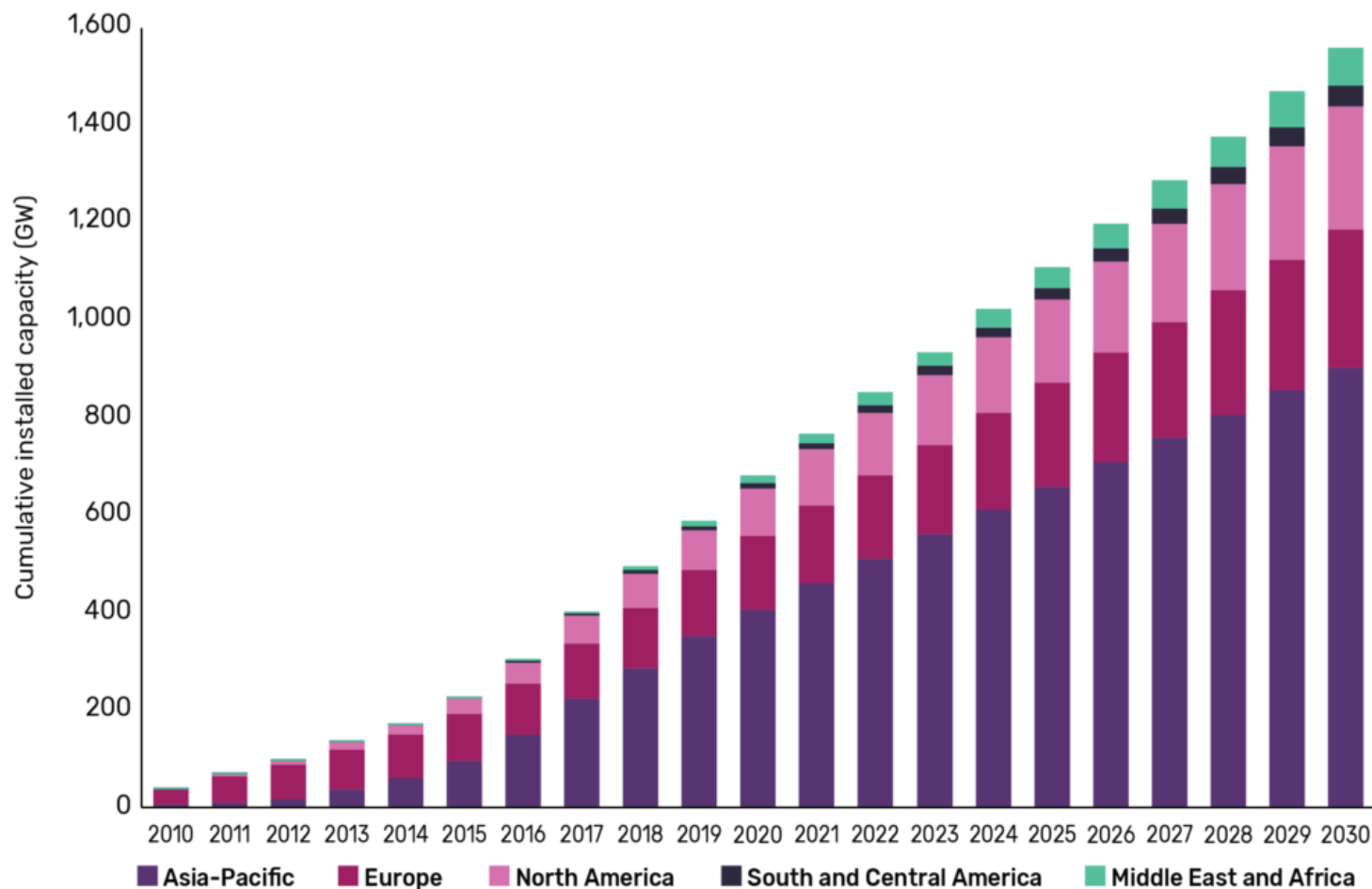
## **III. Four PhD studies supervised between 2014 and 2022**

- **PV plants of Sourdun (Île-de-France) and of Melouka (Algeria)**
- **UV accelerated test platform OSED-aging**
- **Model of a PV grid-connected system**
- **Model of a GaAs solar cell in outer space**

## **IV. Conclusion and perspectives**

# I. Diversity of photovoltaic systems

## Cumulative global solar PV installed capacity by region 2010-2030



Source:  
GlobalData  
Power  
Intelligence  
Center

# I. Diversity of photovoltaic systems

## PV grid-connected systems

### Integration of three PV façades

Building of the Tourist Office in Alès, France  
9,5 kW



### Rooftop photovoltaic plant

La Haye-les-Roses, Val de Marne, Paris, France  
4,3 MW



### Power plants

Copper Mountain Solar Facility in  
Nevada, USA  
458 MW



### The world's first solar road

Tourouvre-au-Perche in Normandy, France



### Full roof BIPV

Umwelt arena Spreitenbach, Zurich, Switzerland  
750 kW



### Floating solar PV

O'MEGA I project, Piolenc,  
Vaucluse, France  
17 MW



# I. Diversity of photovoltaic systems

## Autonomous system

**Solar water pump**  
900 W



**Sign board**  
~ 100 W



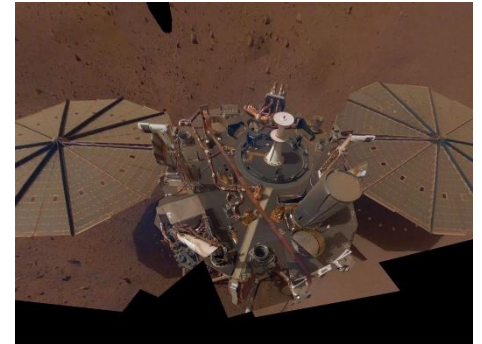
**Helios solar plane**  
~ 35 kW



**Jason-I satellite**  
Earth observing system, 2001  
500 W



**InSight probe on Mars**  
Geology, 2019  
600 W



**Rovers on Mars**  
Sojourner mission 1996  
450 W

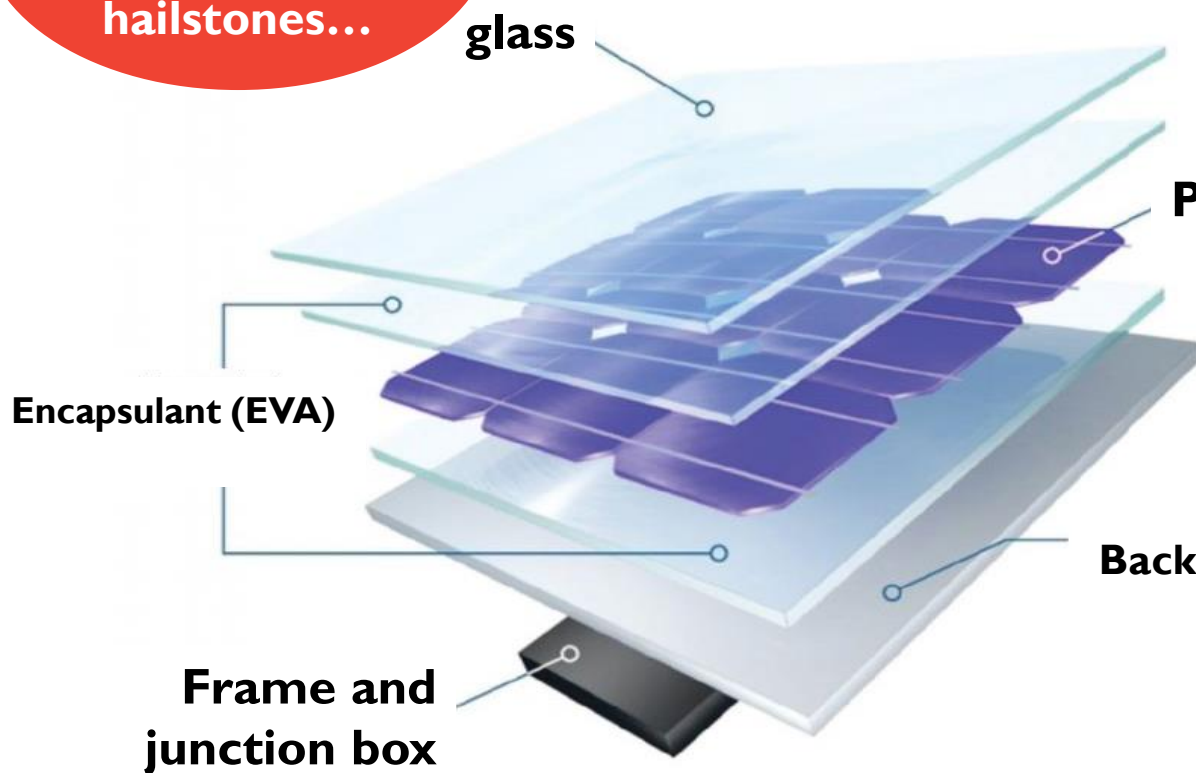




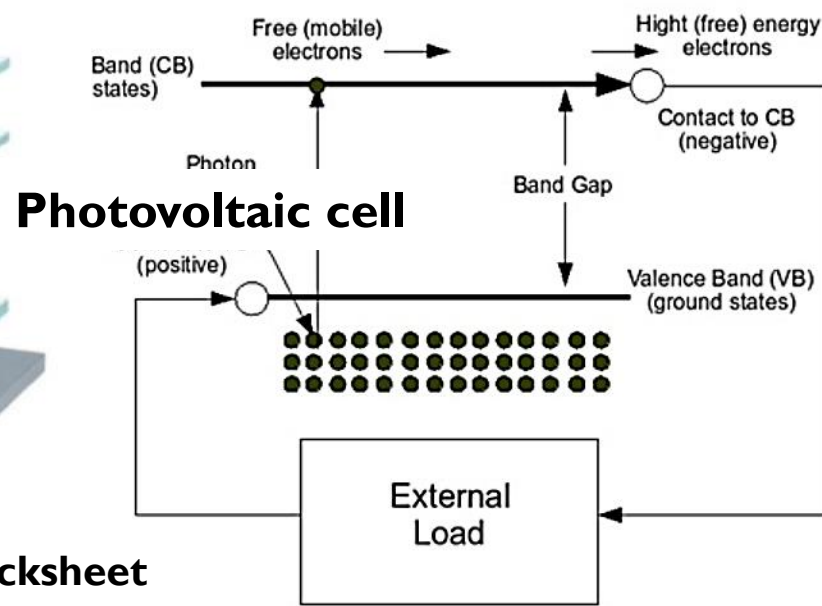
## II. Degradation of PV modules

Irradiance  $T^\circ$ ,  
wind speed,  
snow, sand,  
hailstones...

### Encapsulation of the PV cell



### PV conversion of Si cell



Efficiencies 18%–22% under STC

## II. Degradation of PV modules

### Degradation modes : optical parts

**Soiling**



**Yellowing (browning)**  
**Glass cracks**



**Delamination**



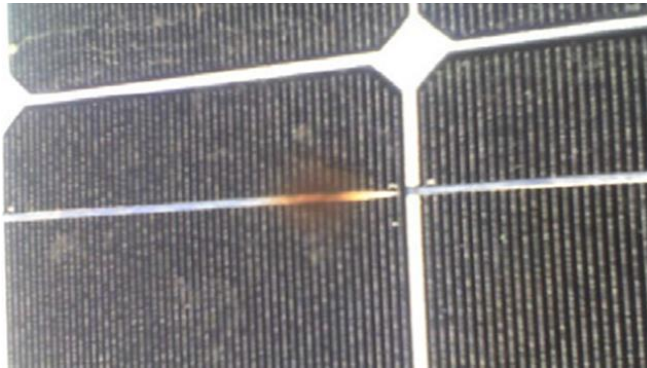
**Sealing problems (moisture ingress)**



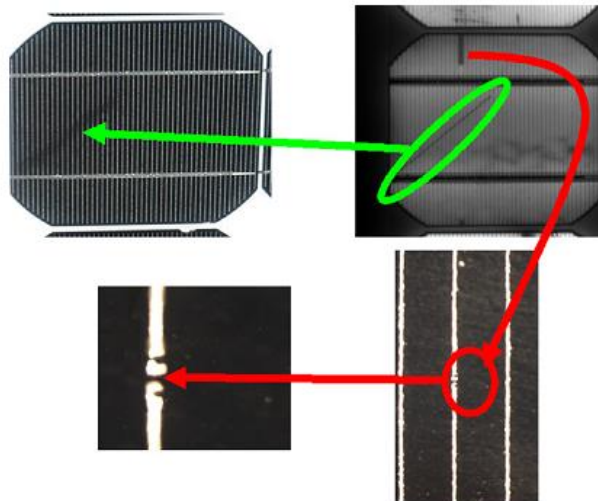
## II. Degradation of PV modules

### Degradation modes : electrical parts

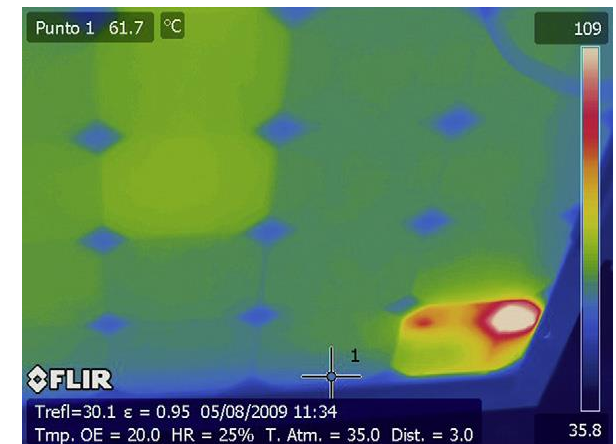
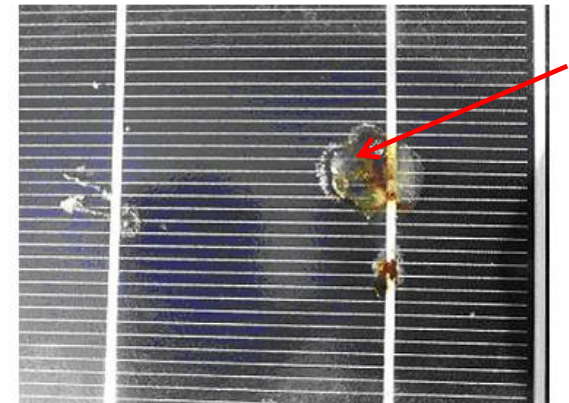
#### Corrosion



#### Microcracks (electroluminescence )



#### Hot spots (IR thermography)

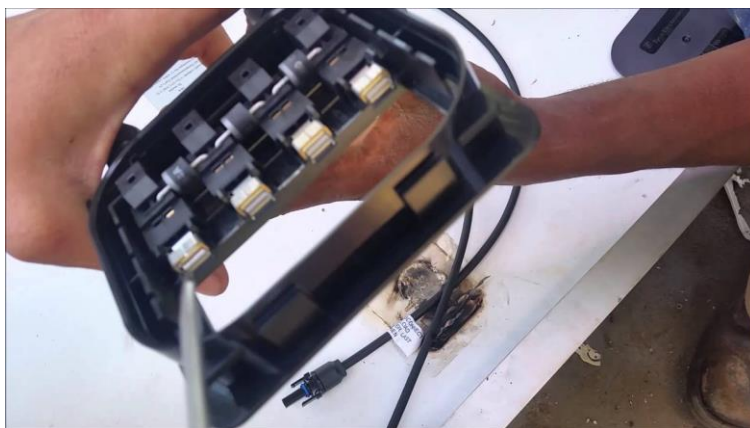




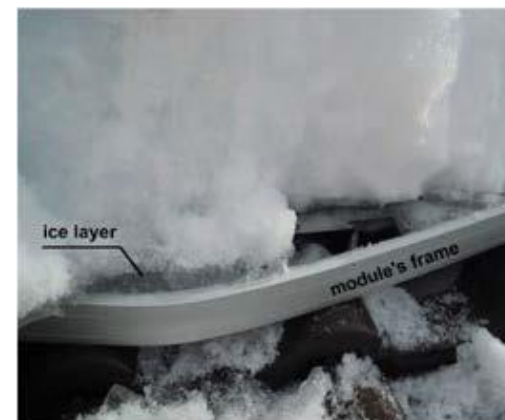
## II. Degradation of PV modules

### Degradation modes : electrical parts

#### Junction box replacement



#### Mechanical load (snow, hail)



#### Detachment of the frame

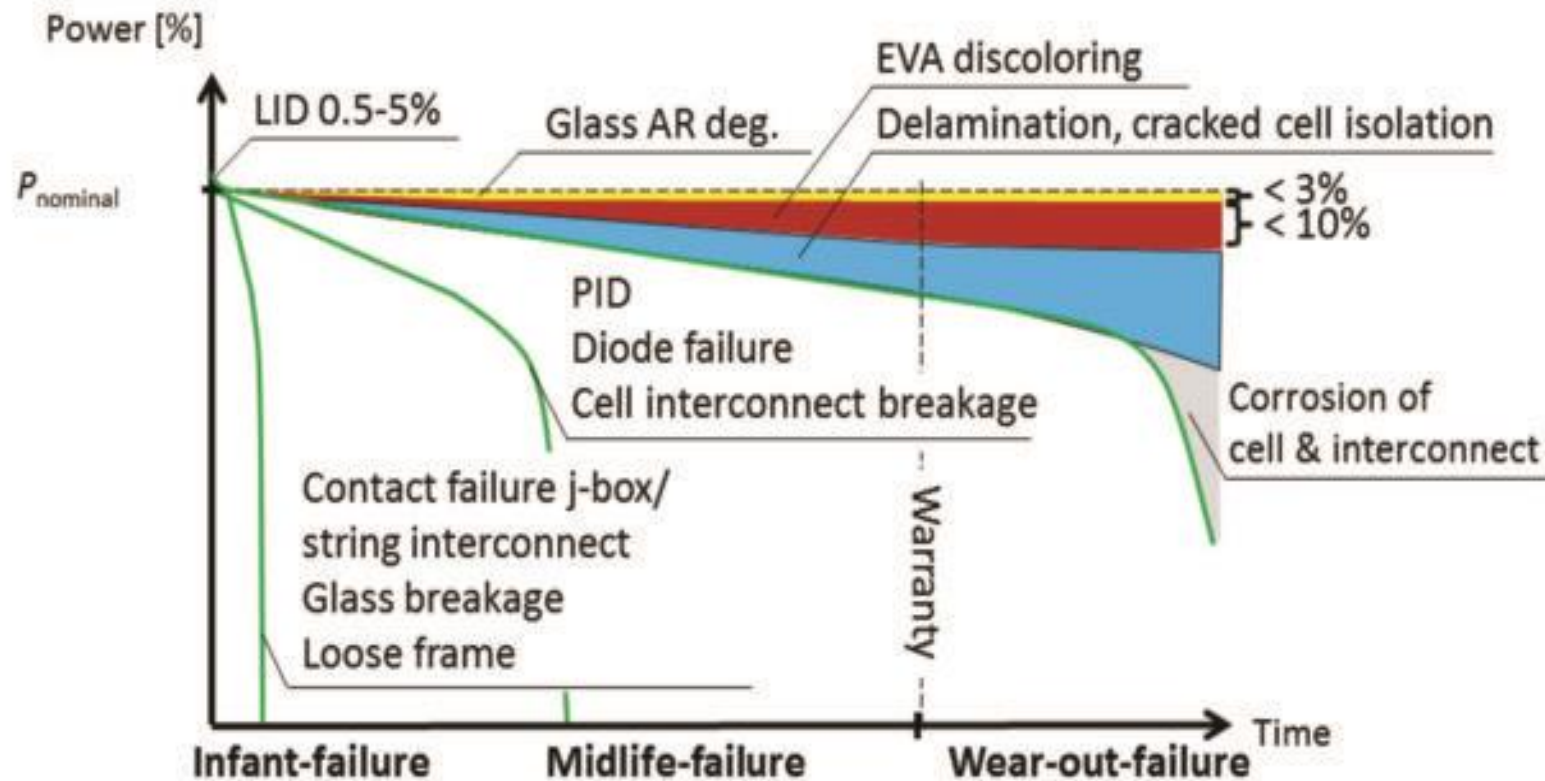


## II. Degradation of PV modules

### Scenarios for wafer-based crystalline photovoltaic modules

LID – light-induced degradation ; PID – potential induced degradation

EVA – ethylene vinyl acetate ; j-box – junction box



*Review of Failures of Photovoltaic Modules, IEA, Report IEA-PVPS T13-01:2014*

## II. Degradation of PV modules

### Key benefits of environment-specific degradation rates

#### Technical benefits

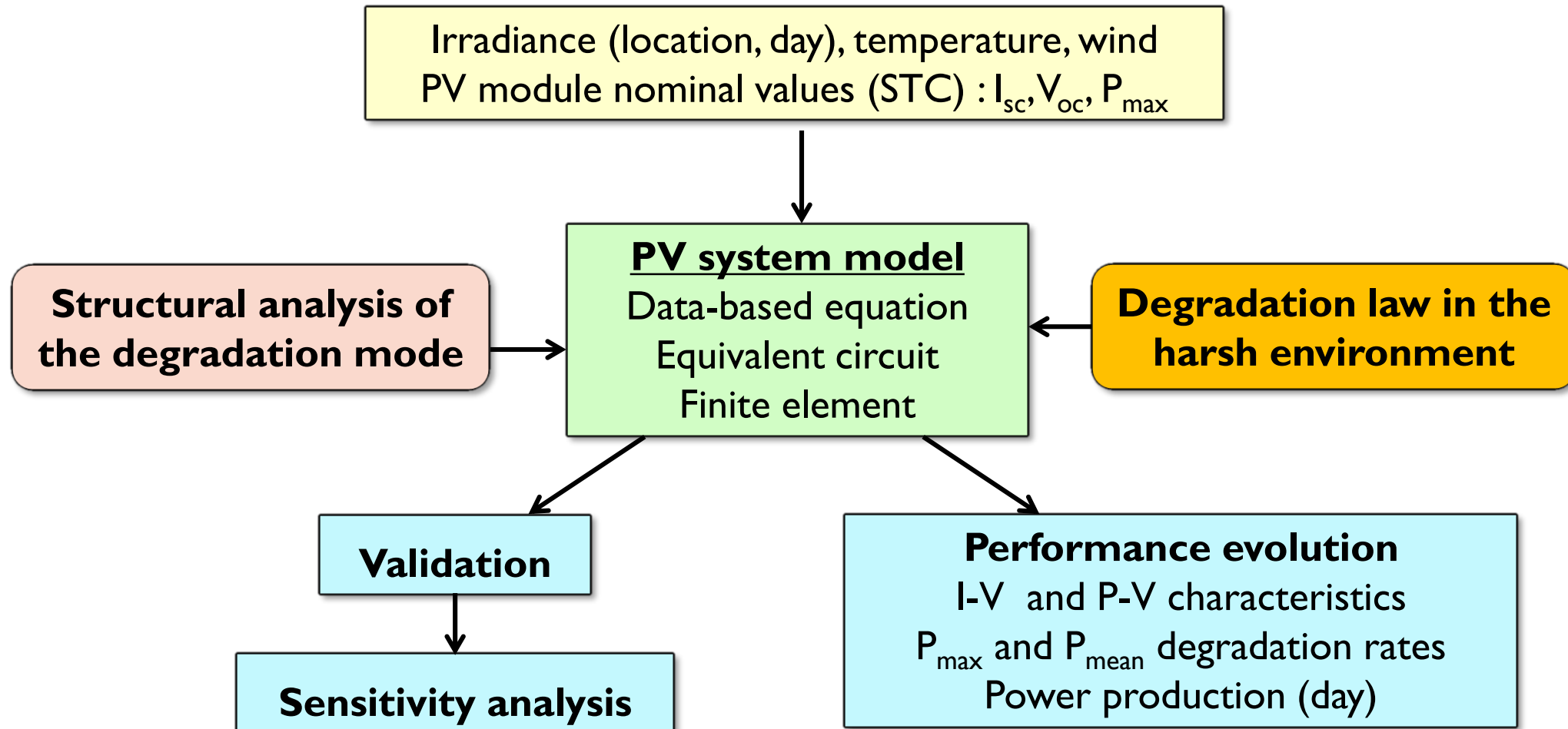
- Performance closer to current technological conversion limit
- Fitting of PV cell technology to operation environment from the start
- Easy repowering of PV plants
- Reliability and durability of PV materials
- Preventive maintenance

#### Economical benefits

- Cumulative yield increase over lifetime
- Dependability of ROI
- Reduced maintenance costs
- Low-energy (lower carbon footprint)

## II. Degradation of PV modules

### Quantifying the impact of aging on performance





# III. Studied systems

Photovoltaic system	Power scale	Environment	PV system model	Aging law	Validation	Sensible parameter	Knowledge
<b>Plant Sourdun (France)</b>	MW	temperate climate	Data-based equation from IEC 61724 analysis	PR degradation rate	Difference vs. real production < 1%	Irradiance and temperature	Relation $E_{out} = f(G)$
<b>Plant Melouka (Algeria)</b>	MW	Desert	Equation based on in-situ I-V measurement	$P_{max}$ degradation rate	Degradation rates in literature	Observed degradation modes	Degradation rate of 1.22%/year
<b>PV conversion line (MPPT + passive filter)</b>	kW	Hot temperate climate	Equivalent circuit	Transmissivity $\tau(t)$ Resistances $R_i(t)$	Degradation rates in literature	Electrical resistances	30% power reduction after 20 years
<b>Supercapacitor storage PV energy</b>	100 W	temperate climate	Equivalent circuit	Transmissivity $\tau(t)$ Resistances $R_i(t)$ Capacitances $C_i(t)$	Outdoor measurement on a test bench	Capacitance of aged supercapacitors	Charge/discharge dynamics
<b>Mono-Si PV panel with load in DH conditions</b>	100 W	Damp heat	Equivalent circuit	Transmissivity $\tau(t)$ Resistances $R_i(t)$	Agreement with the case of Miami, USA	Optical degradations	Energy production projection for 25 years
<b>PV cell with cracked Si cell</b>	10 W	Snow	Physical-based equation	Inactive area	Agreement with values in the literature	Cracked surface	Energy loss over one given day
<b>GaAs, InP junctions in space</b>	W	Electron and proton irradiations in outer space	Finite element	Hole and electron traps Dose of particles	Agreement with DLTS measurements and satellite mission results	Recombination centers	Degradation of $P_{max}$ and efficiency over time

# III. Studied systems

## PV plant of Sourdun (i)

**In the Seine-et-Marne area**

4,5 MW<sub>p</sub>

12 acres of land

p-Si modules

temperate climate



In service since March 2012

Exploited by the Générale du solaire



### III. Studied systems

#### PV plant of Sourdun (ii)

#### Performance study from January 2012 up to December 2018:

**Monitored parameters:**  $G, E, P, T_{\text{mod}}, T_a, v$  (timestep of 15 minutes)

Calculation of the **parameters specified by IEC 61724 standards (2017)** :

- reference yield:  $Y_r = \left( \frac{H_t}{G_0} \right)$

- final yield:  $Y_f = \left( \frac{E_{ac}}{P_0} \right)$

- availability:  $D = 1 - \left( \frac{\text{sum}(DI \times TP)}{DPR} \right)$

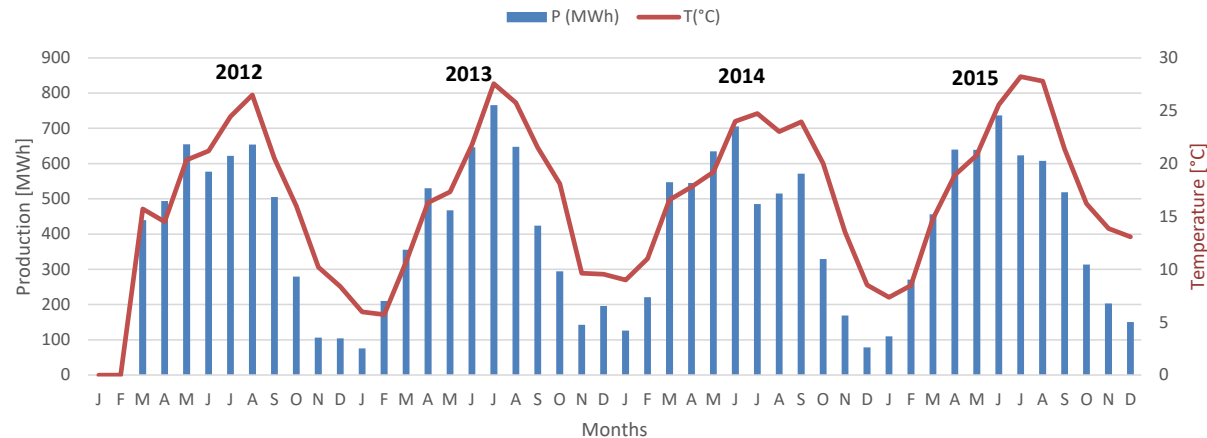
- performance ratio:  $PR = \left( \frac{Y_f}{Y_r} \right)$

- corrected performance ratio:  $PR_c = \left( \frac{PR}{1 + \alpha(T_m - T_n)} \right) \Rightarrow \text{Degradation rate}$

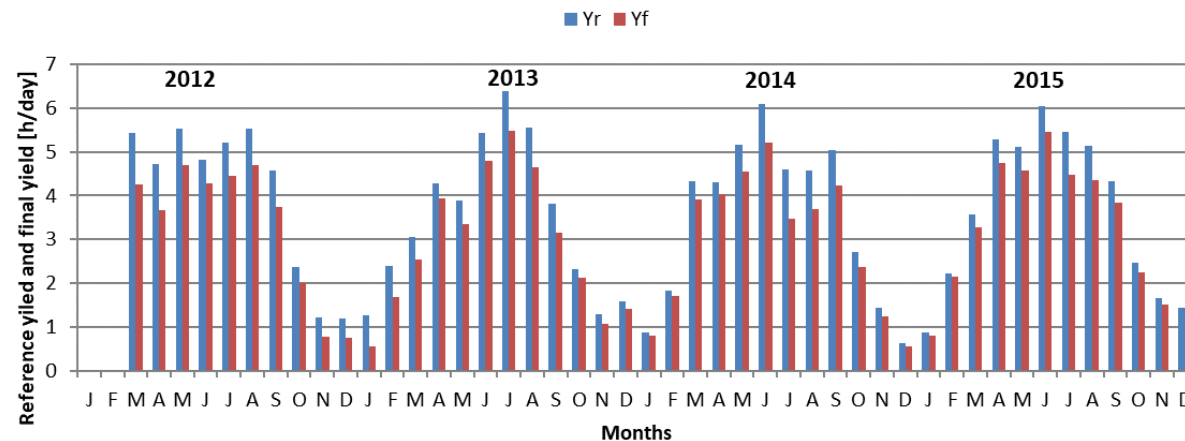
# III. Studied systems

## PV plant of Sourdun (iii)

### Monthly evolution of production and ambient temperature



### Monthly evolution of daily reference yield and final yield

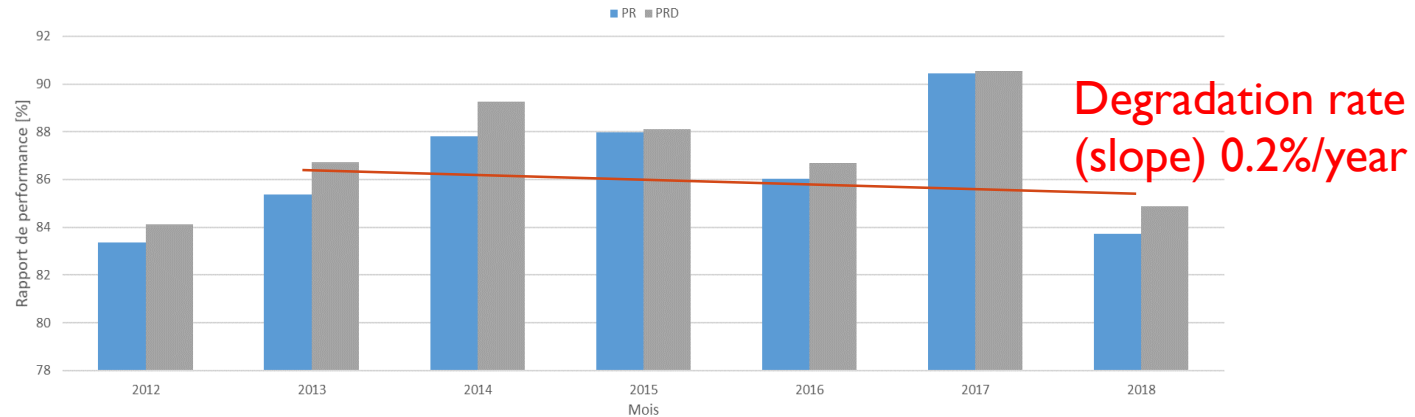




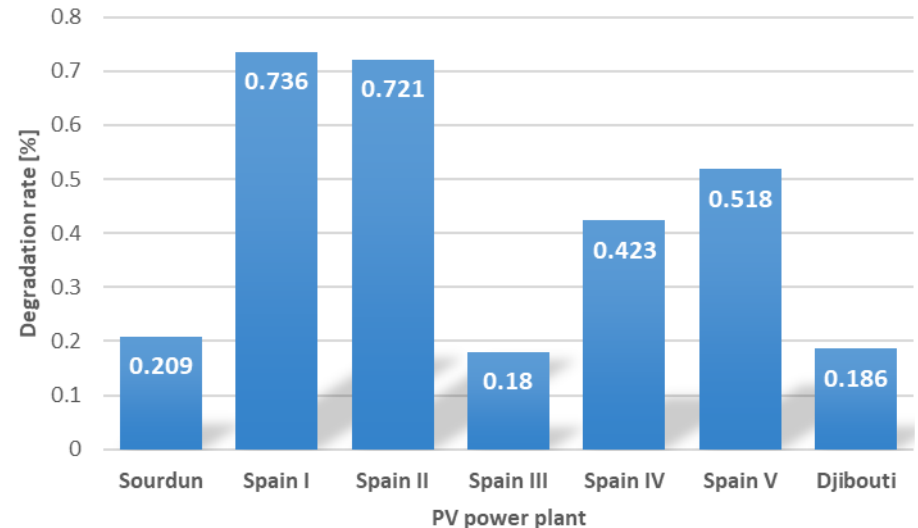
# III. Studied systems

## PV plant of Sourdun (iv)

### Monthly evolution of production and ambient temperature.



**Degradation rate regarding other PV installations studied within IEC 61724 standard.**



*M. Jed et al., Int. J. Sustainable Engineering, 14(6), 2021*

# III. Studied systems

## Melouka PV installation (i)

### Region of Adrar (Ageria)

30.24 kW<sub>p</sub>

864 PV Si-modules of type Belgosolar

48 strings of 18 modules

Inclination 17.5°

In service since 1985

Experimental studied with the CDER



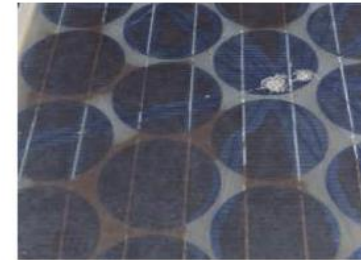
# III. Studied systems

## Melouka PV installation (ii)

**Degradations observed during the survey of photovoltaic modules of the site after 28 years in operation.**



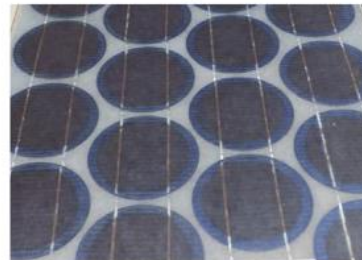
**M01:** Dark brown discoloration of EVA encapsulant



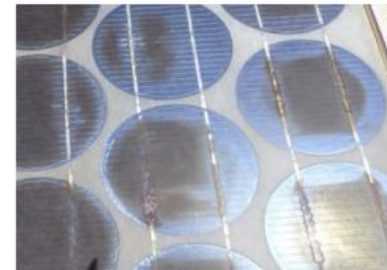
**M02:** Broken front glass



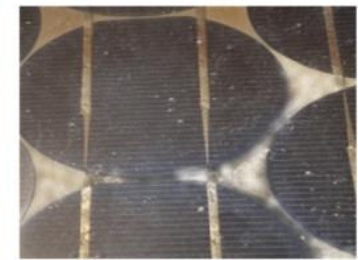
**M03:** Abrasion of glass



**M04:** Higher degree of browning of cells



**M05:** Reddish discoloration on front grid fingers



**M06:** Delamination of encapsulant



**M07:** Yellowing of encapsulant



**M08:** Hot spots in the area of the cells



**M09:** Thermal shocks

*F. Bandou et al., IJHE, 14(6), 2021*

# III. Studied systems

## Melouka PV installation (iii)

### In-situ measurements of I-V curves after 27 years in operation:

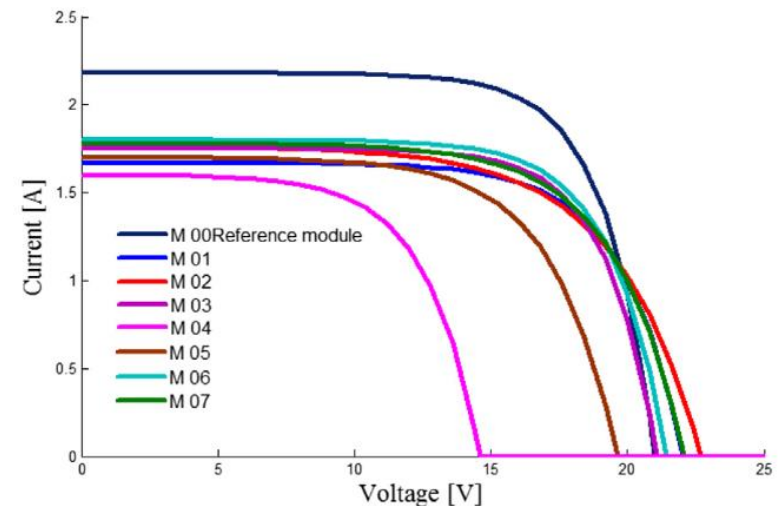
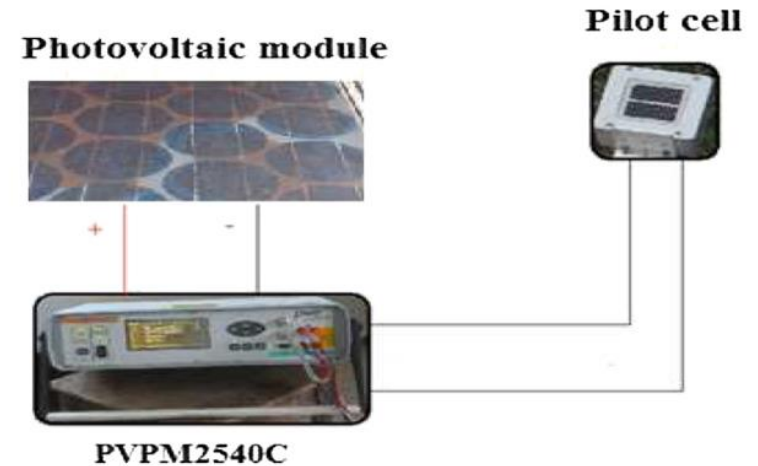
STC translation equations using IEC 60891  
translation procedure:

$$I_{max,STC} = I_{max,mes} \left( \frac{G_{STC}}{G_{mes}} \right) + \alpha(T_{mod} - T_{STC})$$

$$V_{max,STC} = V_{max,mes} - \beta(T_{STC} - T_{mod})$$

$$P_{max,STC} = I_{max,STC} \times V_{max,STC}$$

I-V characteristic curves of the M01-M07 modules tested outdoor translated to standard test conditions (1000 W/m<sup>2</sup>, AM1.5 and cell temperature 25°C).





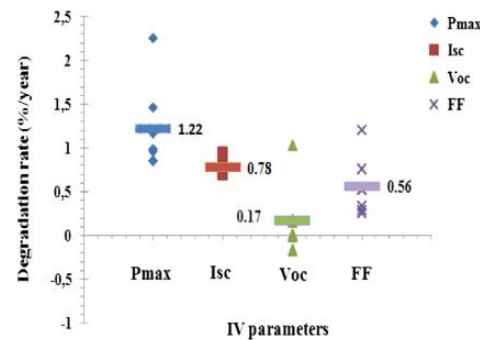
# III. Studied systems

## Melouka PV installation (iv)

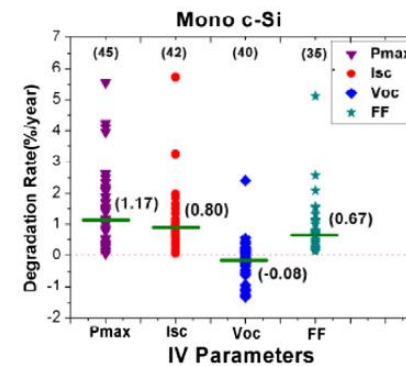
### Degradation rate of the maximum power:

Module	Uncertainties				$P_{\max} \pm u(P_{\max})$ (W)	$R_D \pm u(R_D)$ for $P_{\max}$ (%/year)
	Current $u(I_{\max})$	Voltage $u(V_{\max})$	Irradiance $u(G_{\text{mes}})$	Temperature $u(T_{\text{mod}})$		
M01	0.09	0.05	0.45	0.26	$23.54 \pm 1.09$	$1.17 \pm 0.04$
M02	0.01	0.04	1.47	0.63	$25.56 \pm 0.64$	$0.96 \pm 0.03$
M03	0.01	0.25	0.60	0.35	$26.56 \pm 0.85$	$0.86 \pm 0.02$
M04	0.03	0.57	5.76	1.32	$12.88 \pm 1.42$	$2.26 \pm 0.08$
M05	0.03	0.03	0.46	0.43	$20.58 \pm 0.58$	$1.74 \pm 0.06$
M06	0.05	0.034	4.58	0.41	$25.31 \pm 0.53$	$0.99 \pm 0.03$
M07	0.012	0.08	0.71	0.16	$26.68 \pm 0.68$	$0.85 \pm 0.03$
Mean values					$23.02 \pm 0.83$	$1.22 \pm 0.04$

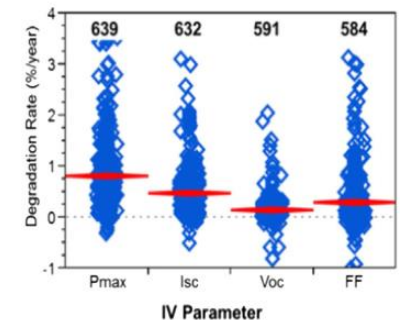
### Comparative results of yearly degradation rates:



(a) : Results provided by our study.



(b) : Results provided by Dubey et al., 2014



(c) : Results provided by Jordan et al., 2012

*F. Bandou et al., IJHE, 40, 2015*

# III. Studied systems

## UV accelerated test (i)

### OSD-aging platform (Sénart)

#### The UV chamber

- Brand : INVE 2000, Helios Quartz
- Chamber temperature at  $50^{\circ}\text{C} \pm 5^{\circ}\text{C}$
- 500 W medium-pressure mercury UV lamp
- Incident irradiance fixed at  $600 \text{ W}/\text{m}^2$  in the wavelength range  $[250 - 400 \text{ nm}]$ .



#### The solar simulator

- Brand : SolarLight type LSI1000-6S
- Class-A for the spectral match and temporal instability classification ( $\pm 5 \%$ )
- Class-B for the irradiance uniformity ( $\pm 10 \%$ )
- Source is a 1000 W xenon lamp with an AM 1.5G filter.
- Temperature-controlled vacuum to maintain STC conditions



### III. Studied systems

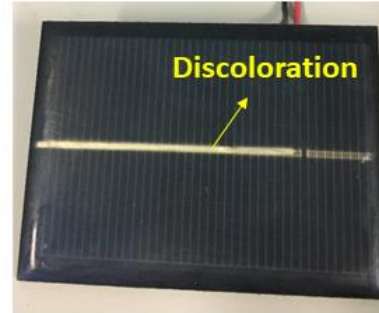
#### UV accelerated test (ii)

**UV test applied to samples encapsulated crystalline-Si PV cells with progressive UV doses**  
(indoor temperature 50°C)

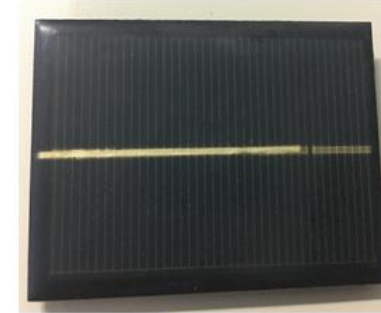
(a) 0 kWh/m<sup>2</sup>



(b) 400 kWh/m<sup>2</sup>



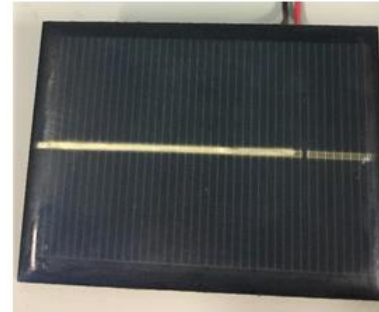
(c) 600 kWh/m<sup>2</sup>



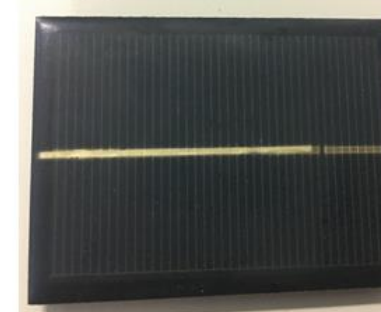
(d) 0 kWh/m<sup>2</sup>



(e) 400 kWh/m<sup>2</sup>



(f) 600 kWh/m<sup>2</sup>



*Presented by V. R. Posa et al.. JNPV conference, 2020*

# III. Studied systems

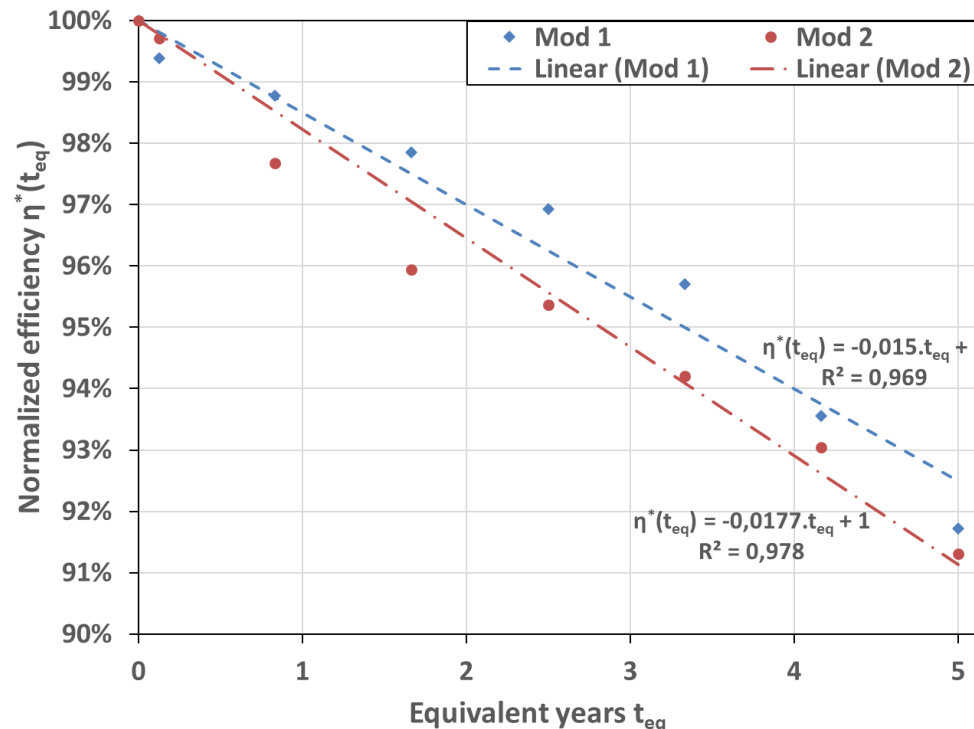
## UV accelerated test (iii)

### Degradation equivalent relation

Outdoor UV dose of 120 kWh/m<sup>2</sup> ⇔ 1 year exposure in PV modules operating in the desert environment (M. Koehl, *Proc. of SPIE*, 7412, 2009) => **Test time in equivalent years**

Normalized efficiency:

$$\eta^*(t_{eq}) = \frac{\eta(t_{eq})}{\eta(t=0)}$$



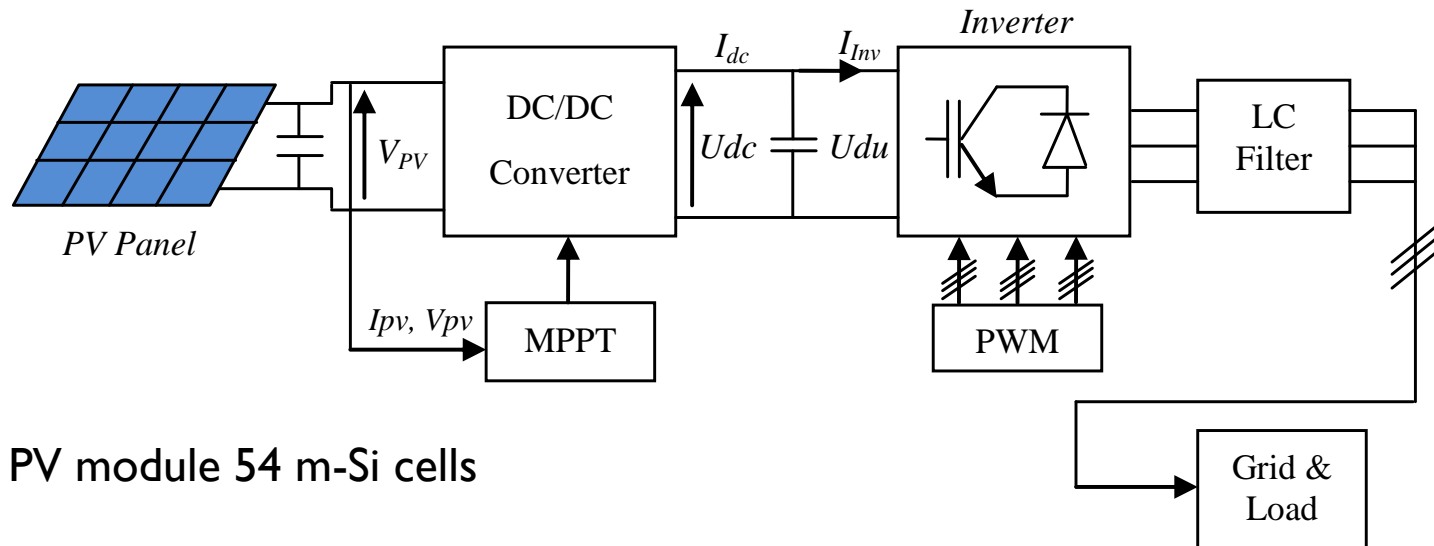
**Degradation rate**  
**1.65%/year**



# III. Studied systems

## Grid-connected PV module (i)

### Modeled photovoltaic conversion line



KC200GT PV module 54 m-Si cells

MPPT: P&O: Perturb and Observe

Passive LC filter

Sizing of the system

A. Azizi et al.. *Solar Energy*, 174, 2018

**=> Matlab/Simulink model**

# III. Studied systems

## Grid-connected PV module (ii)



### Hybrid detection method introducing aging laws

**MPP Tracking:** time  $t \ll T$  (inter-annual time)

**Aging laws:**

85°C/85% RH damp Heat on c-Si modules

**Equivalent time:** 1000 hours test time  $\Leftrightarrow$  20 years of outdoor exposure (*IEC 61215 standards, 2016*)

- **Linear reduction of the transmissivity  $\tau$**  (glass optical losses and encapsulating losses):  $\tau(T) = \tau_0(-\alpha_{opt} \cdot T + 100\%)$   $\alpha_{opt} = 0.6 \text{ \%/year}$  (*King et al., 2000*)
- **Linear augmentation of the series resistance  $R_s$**  (deterioration of electrical parts):  $R_s(T) = R_{s0}(+\alpha_{R_s} \cdot T + 100\%)$   $\alpha_{R_s} = 0.23 \text{ \%/year}$  (*Hulkoff, 2009*)

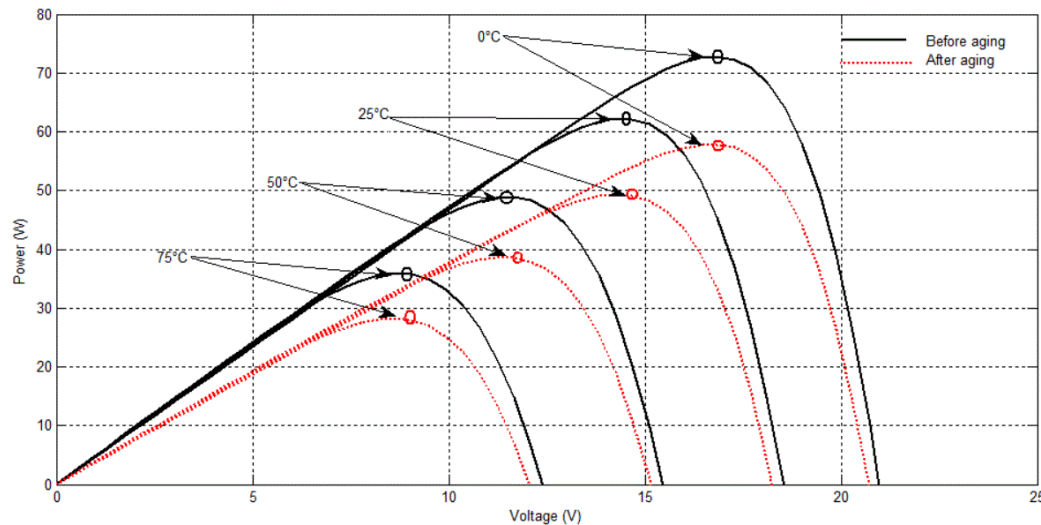
A.Azizi et al.. Solar Energy, 174, 2018

# III. Studied systems

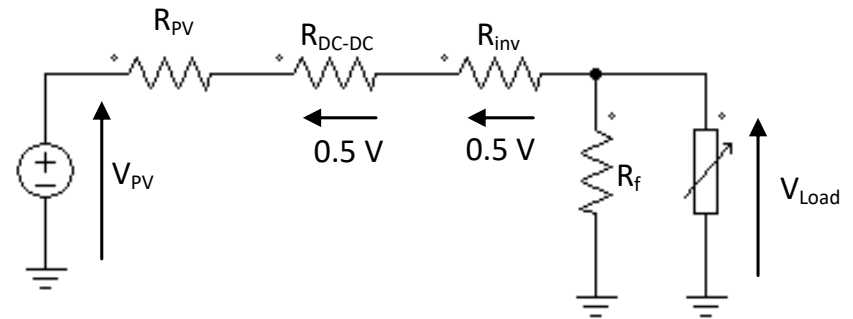
## Grid-connected PV module (iii)

### Outcomes

**Impact of aging with influence of the temperature  
P-V characteristics after 20 years.**



**Equivalent circuit of the photovoltaic  
system with aging resistances**



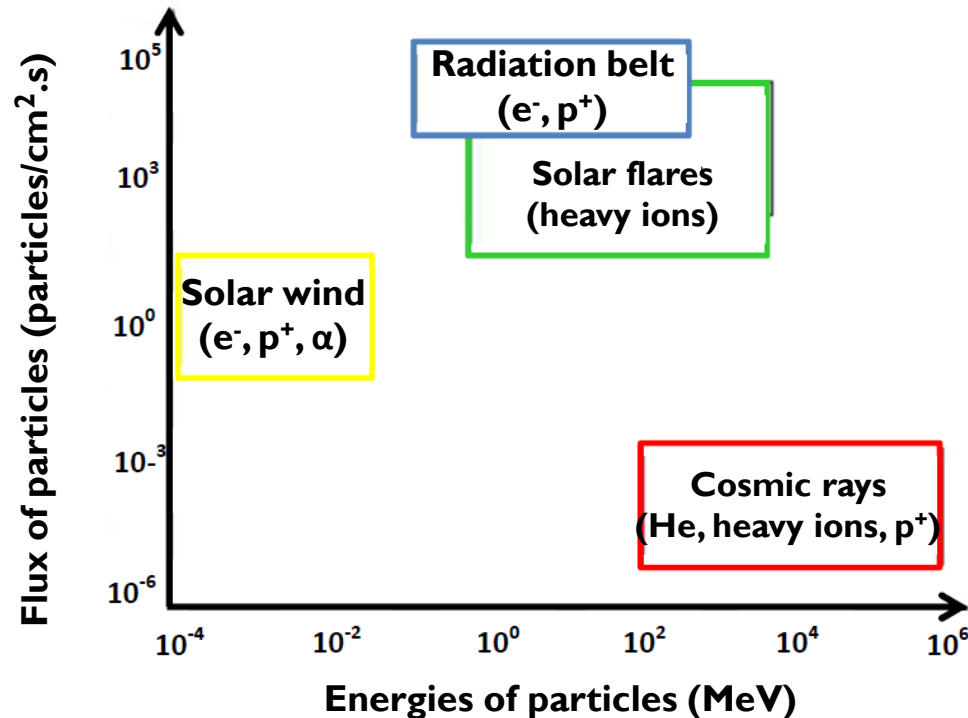
*A. Azizi et al.. Solar Energy, 174, 2018*

# III. Studied systems

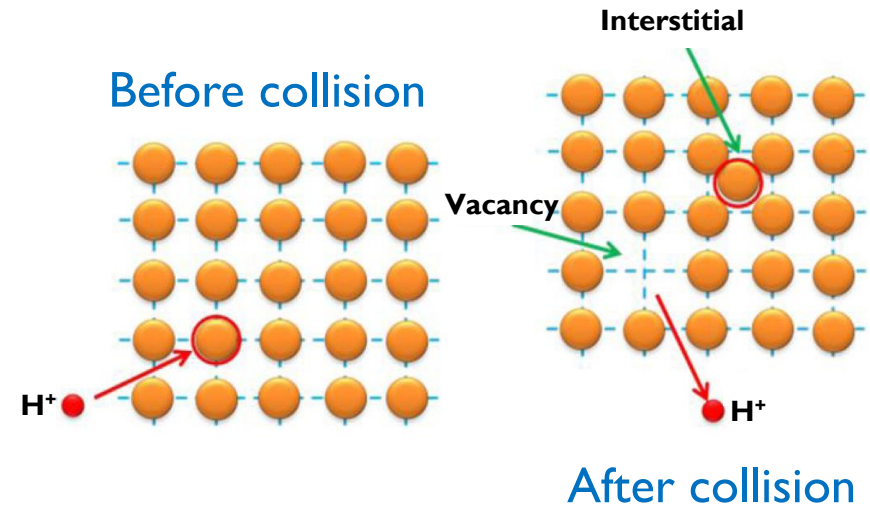
## GaAs solar cell in space (i)



### Flux and energies of particles



### Displacement of an atom by a proton



### Consequences

- Trapping of carriers
- Deep level defects
- Generation of electron-hole pairs
- Recombinations
- Doping compensation
- Tunnel effect

# III. Studied systems

## GaAs solar cell in space (ii)

### Modeling of the PN junction

**Poisson's continuity equations:**

$$\left\{ \begin{array}{l} -\nabla \cdot (\varepsilon \cdot \nabla \psi) = q(p - n + N) \\ \frac{dJ_n}{dx} = -q(G_{opt} - R_{SRH}) \\ \frac{dJ_p}{dx} = q(G_{opt} - R_{SRH}) \end{array} \right.$$

**Optical generation:**

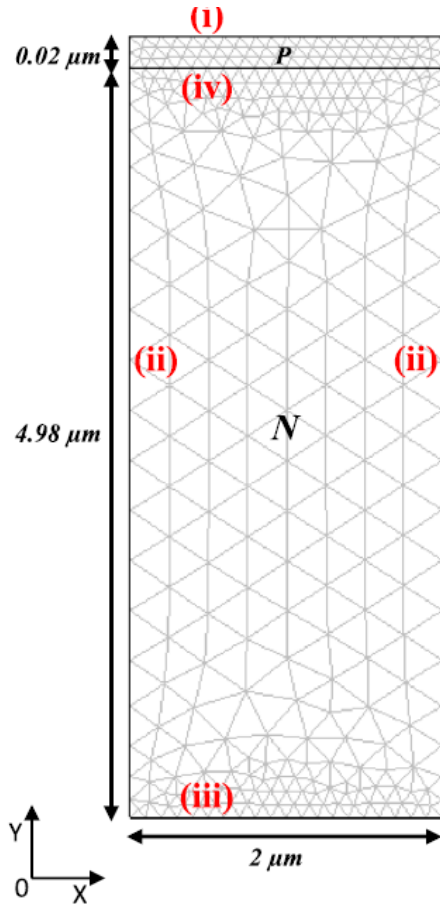
$G_{opt} = (1 - R) \cdot \alpha(\lambda) \cdot \phi \exp(-\alpha(\lambda) \cdot x)$  with an absorption coefficient :

$$\alpha(\lambda) = K_{abs} \cdot \sqrt{\frac{1,24}{\lambda[\mu m]} - E_g}$$

**Shockley-Read-Hall recombination:**  $R_{SRH} = \sum_{j=1}^m \frac{n \cdot p - n_i^2}{\tau_p \cdot (n + n_t) + \tau_n (p + p_t)}$

**Lifetime of electrons and holes:**  $\frac{1}{\tau_{n/p}} = \frac{1}{\tau_{0n/p}} + \frac{1}{\tau_{radn/p}} + N_t \sigma_{n/p} v_{thn/p}$

in which the trap concentration is associated to the recombination centers  $k$  and to the fluence  $\varphi$  :  $N_t = k \cdot \varphi$





# III. Studied systems

## GaAs solar cell in space (iii)

### Aging properties

#### Parameters of the considered mission

Duration	15 years
Satellite power consumption	15 kW
Electron radiation/year/cm <sup>2</sup> (1 MeV) $R_{radE}$	$1.4 \times 10^{13}$
Proton radiation/year/cm <sup>2</sup> (10 MeV) $R_{radP}$	$2.3 \times 10^{10}$

#### Characteristics of electron and hole traps observed for 1 MeV electron irradiated GaAs solar cells

Electron fluence (e/cm <sup>2</sup> )	Electron traps			Hole traps		
	E	$E_t$ (eV)	$N_t$ (cm <sup>-3</sup> )	H	$E_t$ (eV)	$N_t$ (cm <sup>-3</sup> )
$10^{14}$	E1	Ec-0.14	$1.8 \cdot 10^{13}$	H1	Ev+0.71	$3 \cdot 10^{12}$
	E2	Ec-0.41	$8.2 \cdot 10^{12}$			
	E3	Ec-0.71	$3 \cdot 10^{10a}$			
	E4	Ec-0.90	$8.8 \cdot 10^{11}$			
$10^{15}$				H1	Ev+0.13	$2.2 \cdot 10^{14}$
	E2	Ec-0.41	$2.1 \cdot 10^{14}$	H2	Ev+0.29	$4 \cdot 10^{14}$
	E3	Ec-0.71	$1.7 \cdot 10^{13}$	H3	Ev+0.35	$8 \cdot 10^{13}$
	E4	Ec-0.90	$2.8 \cdot 10^{13}$	H4	Ev+0.71	$6.4 \cdot 10^{13}$
$5 \cdot 10^{15}$				H1	Ev+0.13	$8.9 \cdot 10^{14}$
	E2	Ec-0.41	$4.5 \cdot 10^{14}$	H2	Ev+0.29	$1.5 \cdot 10^{15}$
	E3	Ec-0.71	$3.2 \cdot 10^{13}$	H3	Ev+0.35	$1 \cdot 10^{15}$
	E4	Ec-0.90	$5 \cdot 10^{15}$	H4	Ev+0.71	$1.9 \cdot 10^{14}$
$10^{16}$				H1	Ev+0.13	$8.4 \cdot 10^{14}$
	E2	Ec-0.41	$8.8 \cdot 10^{13}$	H2	Ev+0.29	$1.6 \cdot 10^{15}$
	E3	Ec-0.71	$5 \cdot 10^{13}$	H3	Ev+0.35	$1 \cdot 10^{15}$
	E4	Ec-0.90	$6.5 \cdot 10^{13}$	H4	Ev+0.71	$2.7 \cdot 10^{14}$

Bourgoin, Zazoui, *Semicond Sci Technol* 2002;17:453-60.

# III. Studied systems

## GaAs solar cell in space (iv)



### Aging law

Irradiation data and defects engendered for the GEO mission (*Habraken et al. 2001*)  
Log formalism of the efficiency decay (*La Roche et al. 1993; Yamaguchi 2001*).

**The cumulated dose  $D_{grd}$  (in particles/cm<sup>2</sup>) :**

$$D_{grd} = T. \log (R_{rad} + \varphi)$$

where

$R_{rad}$  : irradiation rate of the electrons (or protons)

$T$  : time in year

$\varphi$  : fluence linked to the introduction rate of the recombination centers  $k$  and to the trap concentration:  $N_t = k. \varphi$

*H. Mazouz et al., IEEE JPV, 9(6), 2019*

# III. Studied systems

## GaAs solar cell in space (v)

### Validation without irradiation

Output parameters	2D simulation	Experiment [Liou 1994]	1D simulation [Laiadi 2008]	2D simulation [Elahidoost 2012]
$J_{cc}$ (mA/cm <sup>2</sup> )	28,58	32,37	23,86	24,08
$V_{co}$ (V)	0,977	1,017	1,01	0,95
$FF$	0,884	0,815	0,88	0,839
$\eta$ (%)	18,30	19,9	15,60	14,1

### Validation under electron irradiation

Fluence (e.cm <sup>-2</sup> )	Before irradiation	$\phi = 10^{14}$			$\phi = 10^{15}$			$\phi = 5.10^{15}$			$\phi = 10^{16}$		
		2D		1D	2D		1D	2D		1D	2D		1D
		modele	ref. [Elahidoost 2012]	ref. [Laiadi 2008]	modele	ref. [Elahidoost 2012]	ref. [Laiadi 2008]	modele	ref. [Elahidoost 2012]	ref. [Laiadi 2008]	modele	ref. [Elahidoost 2012]	ref. [Laiadi 2008]
$J_{cc}$ (mA.cm <sup>-2</sup> )	28,58	25,22	23,81	22,27	17,11	21,63	21,63	15,63	16,95	17,04	11,24	12,26	14,362
$V_{oc}$ (V)	0,977	0,969	0,94	0,88	0,958	0,92	0,92	0,897	0,895	0,706	0,886	0,87	0,678
$FF$	0,884	0,890	0,840	0,796	0,892	0,841	0,841	0,887	0,830	0,751	0,889	0,817	0,730
$\eta$ (%)	18,30	16,12	13,9	11,5	10,84	12,35	12,35	9,21	9,375	6,60	6,56	6,4	5,23

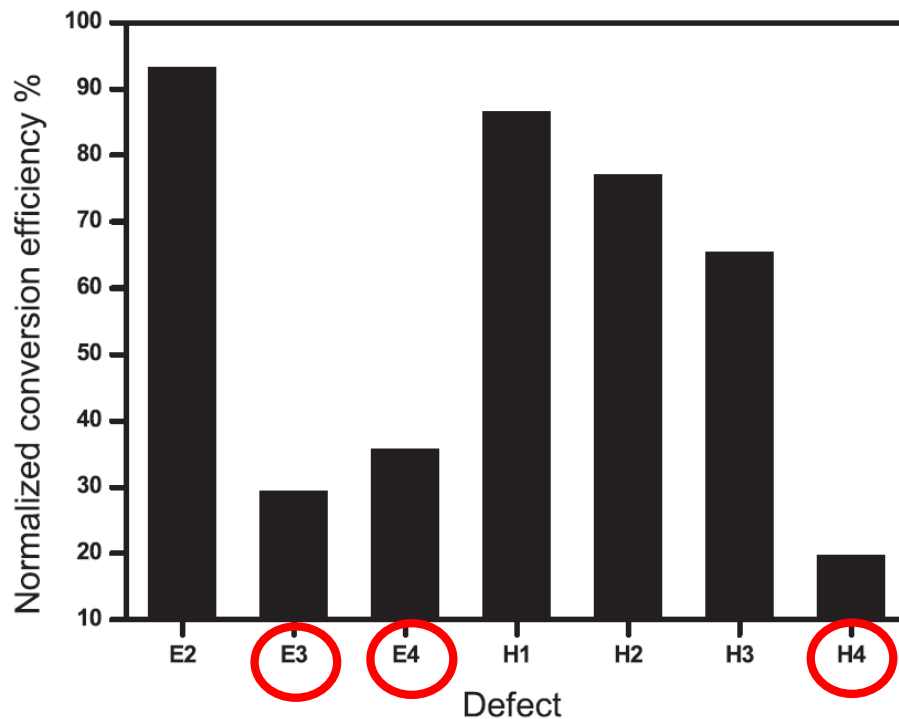
H. Mazouz et al.. IJHE, 40, 2015.

# III. Studied systems

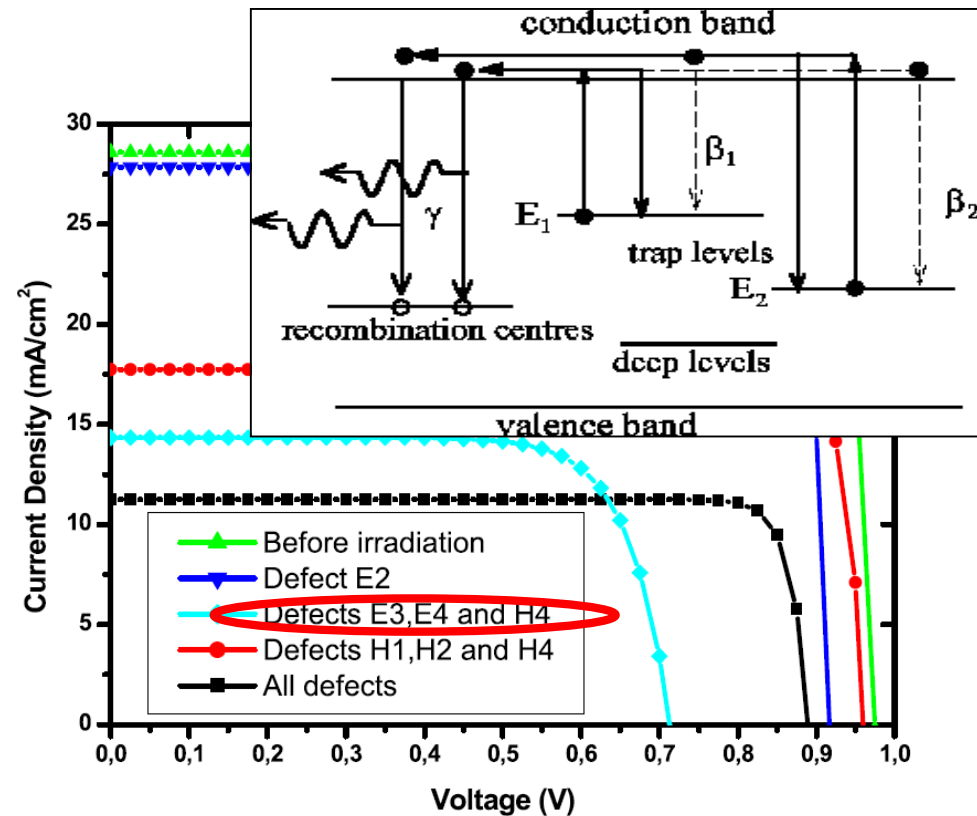
## GaAs solar cell in space (vi)

### Sensitivity analysis

Normalized conversion efficiency  
for the various defects



J(V) characteristics as a function of defect level for the electron fluence of  $10^{16}$  e/cm<sup>2</sup>



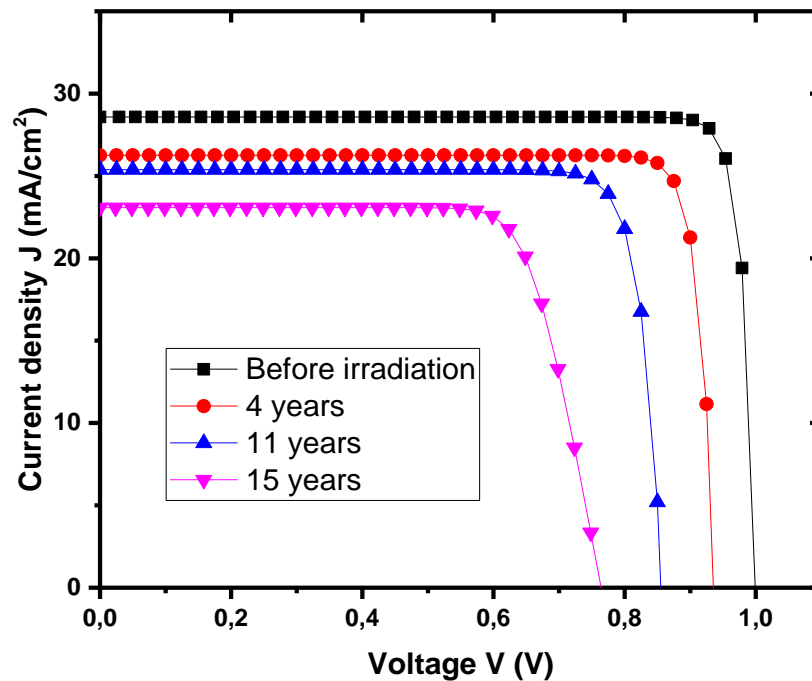
*H. Mazouz et al., IJHE, 40, 2015.*

# III. Studied systems

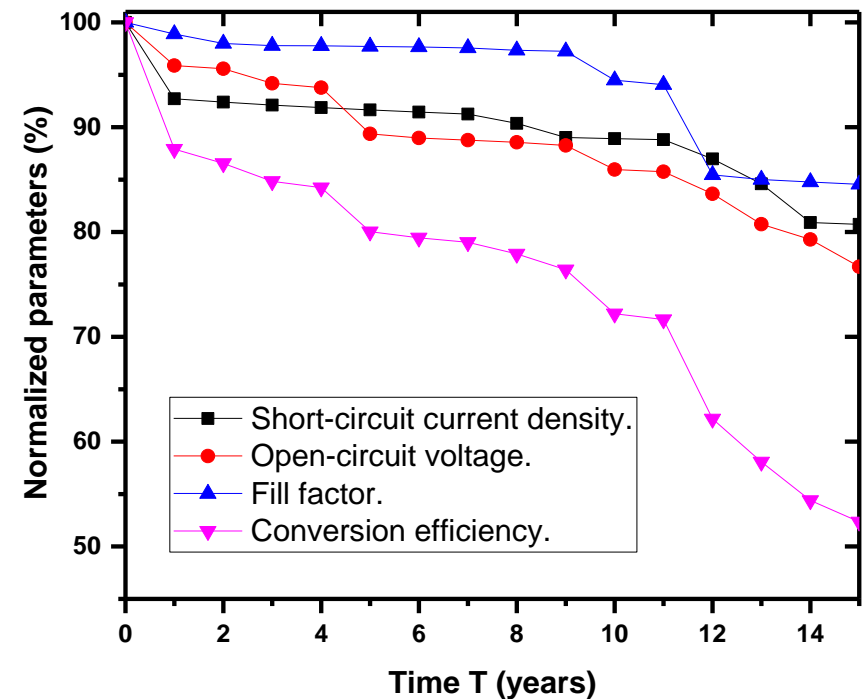
## GaAs solar cell in space (vii)

### Degradation of the performance in outer space

Evolution of the J(V) characteristic



Normalized conversion efficiency degradation with the other simulated output parameters

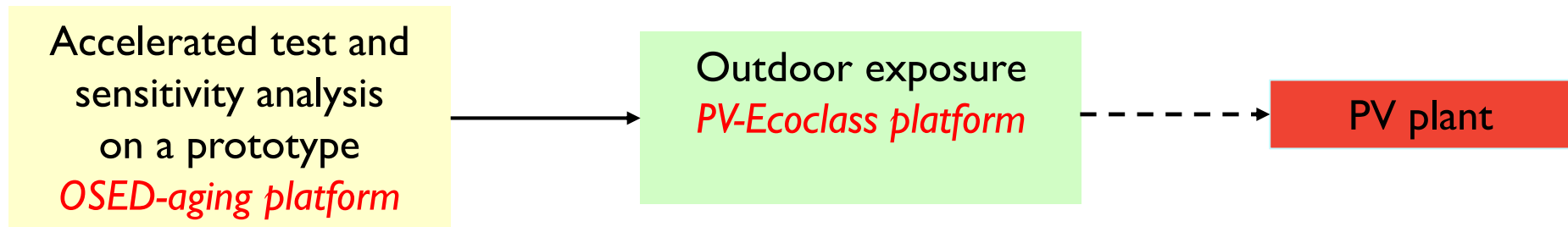


*H. Mazouz et al. IEEE JPV, 9(6), 2019*



## IV. Conclusion and perspectives

- ❑ **Multi-scale approach** **W** → **kW** → **MW** for fitting one PV technology module to one given environment at the CERTES laboratory



- ❑ **PhD students in progress:**
  - **Mohamed El Hacem JED:** defense on October 22th 2022
  - **Julia VINCENT:** sequential accelerated tests on Si PV cells by Slite-Source
  - **Islem BOUJLEL:** sensitivity analysis and energy performance of PV modules, aging of temperature coefficients
- ❑ **Projects and collaborations:** ANAPHORE (OSU-Efluve), TotalEnergies, CERD Djibouti, EMSI (Morocco)



**Thank you for your attention**